NSN 5961-00-404-6742

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-404-6742 **Inclosure Material:** Metal **Overall Length:** 5.500 inches **Overall Height:** 1.000 inches **Overall Width:** 1.000 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20000.0 reverse voltage, peak **Current Rating Per Characteristic:** 500.00 milliamperes forward current, total rms megahertz and 35.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 140.0 degrees celsius ambient air **Test Data Document:** 10001-2841533 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator:** Unc **Terminal Type And Quantity:** 2 threaded hole Shelf Life: N/a **Unit Of Measure:**

Demilitarization: No

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